arXiv:cond-mat/0311010v2 [cond-mat.mes-hall] 29 Apr 2004

Demonstration of a 1/4 cycle phase shift in the radiation-induced oscillatory-magnetoresistance in GaAs/AlGaAs devices

R. G. Mani,[1] J. H. Smet,[2] K. von Klitzing,[2] V. Narayanamurti,[1,3] W. B. Johnson,[4] and V. Umansky[5]

[1]*Harvard University, Gordon McKay Laboratory of Applied Science, 9 Oxford Street, Cambridge, MA 02138, USA*
[2]*Max-Planck-Institut für Festkörperforschung, Heisenbergstrasse 1, 70569 Stuttgart, Germany*
[3]*Harvard University, 217 Pierce Hall, 29 Oxford Street, Cambridge, MA 02138, USA*
[4]*Laboratory for Physical Sciences, University of Maryland, College Park, MD 20740, USA*
[5]*Braun Center for Submicron Research, Weizmann Institute, Rehovot 76100, Israel*

(Dated: February 2, 2008)

We examine the phase and the period of the radiation-induced oscillatory-magnetoresistance in GaAs/AlGaAs devices utilizing in-situ magnetic field calibration by Electron Spin Resonance of DiPhenyl-Picryl-Hydrazal (DPPH). The results confirm a f-independent 1/4 cycle phase shift with respect to the $hf = j\hbar\omega_c$ condition for $j \geq 1$, and they also suggest a small ($\approx 2\%$) reduction in the effective mass ratio, m^*/m, with respect to the standard value for GaAs/AlGaAs devices.

PACS numbers: 73.21.-b,73.40.-c,73.43.-f; Journal-Ref: Phys. Rev. Lett. 92, 146801 (2004)

Measurements [1] of GaAs/AlGaAs devices including a 2-Dimensional electron system (2DES) have recently shown that vanishing resistance can be induced by photo-excitation at liquid helium temperatures, in a weak-magnetic-field large-filling-factor limit.[1, 2, 3] The possibility of identifying a new physical mechanism for inducing vanishing resistance in the 2DES has motivated much theoretical interest in this phenomenon,[4, 5, 6, 7, 8, 9] which shares features of the zero-resistance states in the quantum Hall situation, minus Hall quantization.[10, 11]

Experiments suggest that this novel effect is characterized, in the Hall geometry, by a wide magnetic field, B, interval where the diagonal resistance, R_{xx}, becomes exponentially small upon photo-excitation in the low temperature, T, limit.[1, 2, 12] Measurements have also indicated that increasing the radiation frequency, f, linearly shifts distinguishing features to higher B.[13, 14] Thus, one might define from f a field scale $B_f = 2\pi f m^*/e$, where e is the electron-charge, and m^* is an effective mass.[1] According to theory, the observed periodicity reflects the interplay between the photon energy, hf, and integral (j) cyclotron energies, $j\hbar\omega_c$, and B_f is defined by $hf = \hbar\omega_c$.[4, 6, 8] Hence, in the expression for B_f, e is a known constant, f can be measured accurately, and m^* can be taken, initially, to be the standard value for m^* in GaAs/AlGaAs, although it could involve corrections.

A problem of interest is to identify the B intervals that exhibit vanishing resistance at a fixed f, and to connect them in a simple way to B_f because the relation between the two scales $(hf, j\hbar\omega_c)$, which is set by B, is likely to be essential in the underlying physics. In earlier work, we had reported that resistance minima occur about $B = [4/(4j+1)]B_f$ and resistance maxima transpire about $B = [4/(4j+3)]B_f$, with j=1,2,3... [1] This "minima about $B = [4/(4j+1)]B_f$" result might also be loosely reformulated as a "1/4 cycle phase shift" with respect to the $hf = j\hbar\omega_c$ condition.[15]

Our "minima about $B = [4/(4j+1)B_f]$" result seems incongruent, however, with a report which identified radiation induced resistance minima with $\omega/\omega_c = j+1/2$, i.e., $B_f/B = j+1/2$, and resistance maxima with $\omega/\omega_c = j$, i.e., $B_f/B = j$, where $\omega = 2\pi f$.[14] Briefly, that study of low mobility specimens exhibited T-insensitive R_{xx} oscillations, a large non-vanishing resistance at the minima even at the lowest T, and the absence of a phase shift.[14] A subsequent study of high mobility specimens identified resistance maxima with $\omega/\omega_c = j$, as it placed resistance minima on the high magnetic field side of $\omega/\omega_c = j + 1/2$.[2]

A recent reformulation[16] asserts that the phase of the R_{xx} oscillations in ref.[2] are consistent with a 1/4 cycle phase shift,[1] but only at low-B, i.e., $j \geq 4$. Although this reinterpretation has helped to bring overlap between theory,[4, 6, 8] and recent experiment,[1, 2, 12, 13, 16] there continues to be a phase-variance in the regime of low j, $j \leq 4$, between our initial report announcing these novel zero-resistance states [ZRS], and the report by Zudov et al., confirming the same.[1, 2]

Phase characterization in this context requires an accurate measurement of B since the observed oscillations are referenced to f, which sets B_f. In the laboratory, the transport set-up typically includes a high-field superconducting magnet, and B is often determined from the magnet coil current, I, via a calibration constant. At low-B, $B \leq 0.5T$, this approach to B-measurement can be unreliable due to nonlinearity and hysteresis in the $B - I$ characteristics of the field-coil, and B offsets due to trapped flux and/or current-offsets in the magnet power supply. An in-situ Hall probe can be applied to correct this problem. However, even this approach is prone to field measurement errors arising from misalignment-voltages in the Hall sensor or changes in the Hall constant.[17] To reduce such uncertainties, we have carried out microwave transport studies of the 2DES with in-situ B-field calibration by Electron Spin Resonance (ESR) of DiPhenyl-Picryl-Hydrazal (DPPH). The

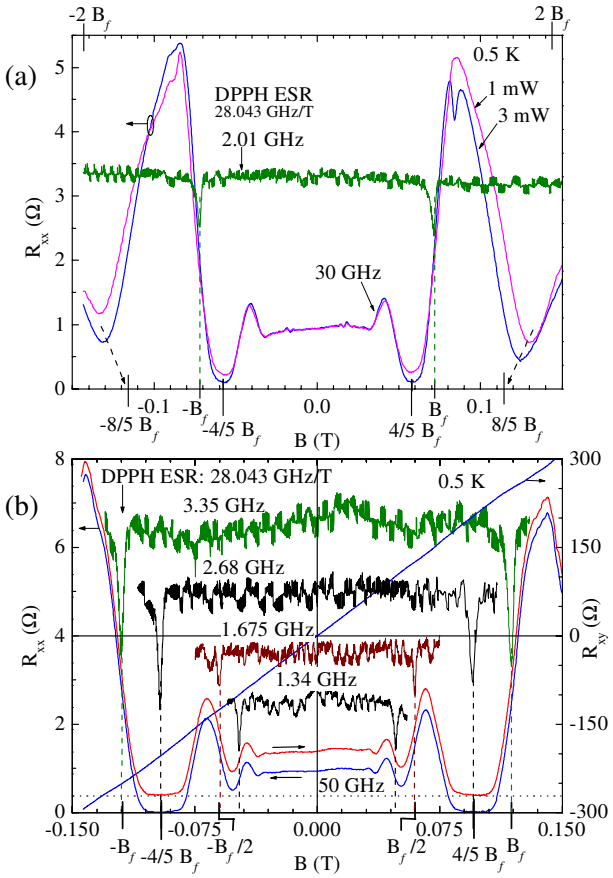

FIG. 1: (a) The magnetoresistance R_{xx} is plotted vs. the magnetic field B for a GaAs/AlGaAs device under photoexcitation at $f = 30$ GHz. Also shown is the Electron Spin Resonance (ESR) of DiPhenyl-Picryl-Hydrazal (DPPH) at 2.01 GHz, which marks $B_f = 2\pi f m^*/e$. R_{xx} exhibits neither a maximum nor a minimum at B_f. A deep R_{xx} minimum between $B_f < B < 2B_f$ appears to converge to $2(4/5B_f) = 8/5B_f$, suggestive of a two photon effect. (b) R_{xx} and R_{xy} at 50 GHz along with DPPH-ESR field markers for B_f, $4/5B_f$, $B_f/2$, and $B_f/2.5$. Note the similarity in the up- and down- sweep R_{xx} curves, and the weak oscillations in R_{xy}. The up-sweep curve has been offset to improve clarity.

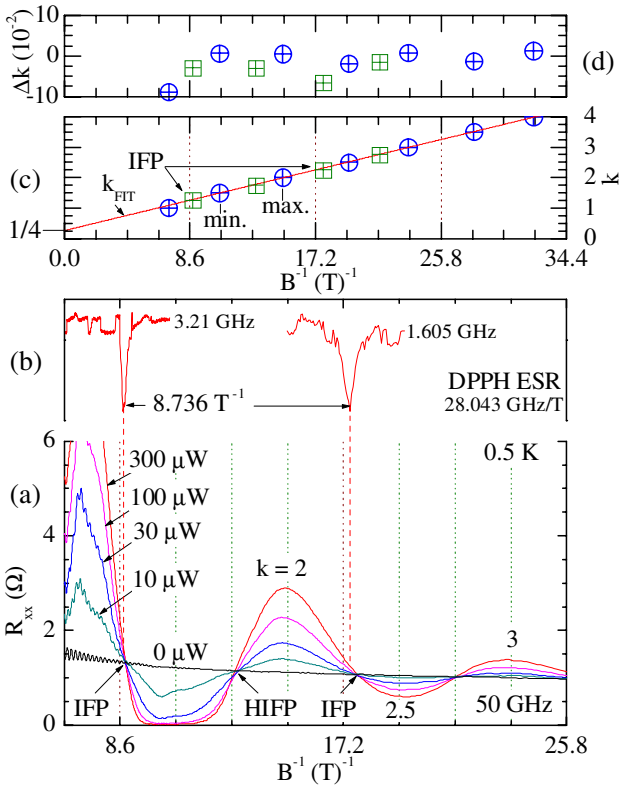

FIG. 2: (a) R_{xx} is shown vs B^{-1} for several radiation intensities at 50 GHz. (b) ESR of DPPH for $f_0 = 3.21$ GHz and $f_0/2 = 1.605$ GHz. Here, f_0 marks the first Integral Fixed Point (IFP) in (a). The period of the R_{xx} oscillations, 8.6 T^{-1}, appears to be slightly smaller than the spacing of the DPPH-ESR lines. (c) A half-cycle plot of the extrema in (a). A linear fit suggests a 1/4 cycle phase shift. Fixed points, inserted as open squares, were not used for the fit. (d) The residue in k, i.e., $\Delta k = k - k_{FIT}$, extracted from (c).

results demonstrate a f-independent 1/4 cycle phase shift in the radiation-induced oscillatory-magnetoresistance, and they suggest a small reduction in the mass ratio characterizing this phenomena, with respect to the standard value for m^*/m, $m^*/m = 0.067$.[18]

Experimental details have been reported elsewhere.[1, 12, 13] Here, for $f \leq 50$ GHz, the samples were photoexcited with a digital-frequency-readout microwave generator, with a 1 *ppm* uncertainty in f in the CW mode.[19] At higher frequencies, mechanical f-meters with an uncertainty of 0.4% above 100 GHz were used in conjunction with calibration tables to determine f.[20] Thus, f is thought to be better characterized below 50 GHz. ESR of DPPH was performed in the immediate vicinity of the 2DES at $f \leq 10$ GHz using a second digital-frequency-readout microwave source.[21] The g-factor for the unpaired electron undergoing ESR on DPPH is 2.0036, which corresponds to 28.043 GHz/T.[22]

Fig. 1(a) shows the magnetoresistance R_{xx} measured in a GaAs/AlGaAs device with microwave excitation at 30 GHz. Also shown is the ESR of DPPH at 2.01 GHz, which marks $B_f = 2\pi f m^*/e$ for $f = 30$ GHz and $m^*/m = 0.067$. The data of Fig. 1 (a) indicate that the ESR field marker coincides neither with a minimum nor with a maximum in the R_{xx} signal.[1] Fig. 1(a) also indicates a strong resistance minimum below B_f, about $4/5B_f$, which is the $j = 1$ member of $B = (4/[4j+1])B_f$. These data at 30 GHz also exhibit a deep minimum between B_f and $2B_f$, which is identified here as the possible principal minimum for a two-photon process with a fundamental field $2B_f$, expected to form about $2(4/5B_f) = 8/5B_f$. The data suggest a convergence to $8/5B_f$, as the minimum becomes deeper with increasing microwave power.

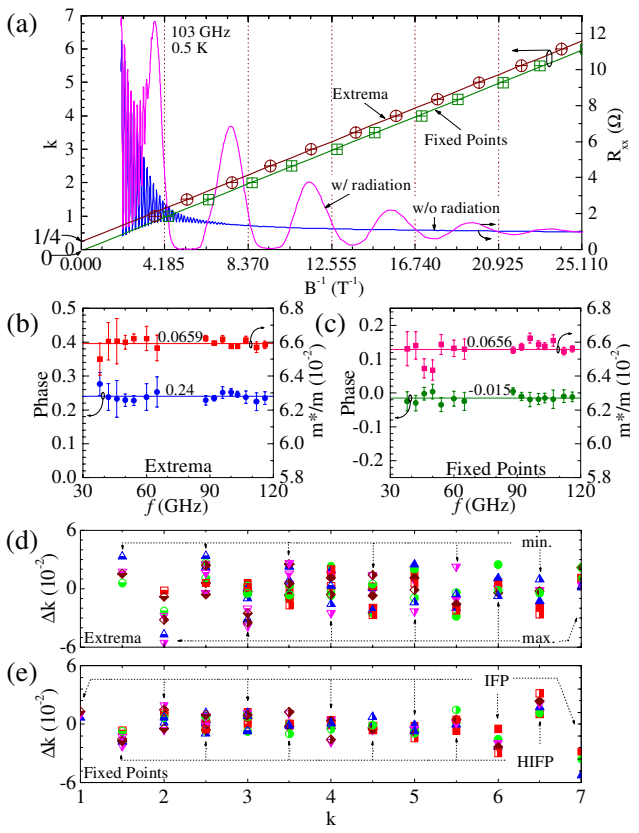

FIG. 3: (a)(right ordinate): R_{xx} is plotted vs. B^{-1} with (w/) and without (w/o) radiation at 103 GHz. (left ordinate) Half-cycle plots of the extrema and the fixed points in the radiation induced resistance oscillations. The slope of the linear fit is proportional to m^*/m, while the ordinate intercept measures the phase. (b): The phase and the effective mass ratio, m^*/m, obtained from linear fits of half cycle plots of extrema [see (a)] as a function of the frequency. (c): The phase and m^*/m obtained from linear fits of half cycle plots of fixed points [see (a)] vs. f. (d): The residue in the extrema labels, $\Delta k = k - k_{FIT}$, is shown as a function of k, the assigned label, for f shown in (b). (e): For the fixed points, Δk is shown vs. k, for f in (c).

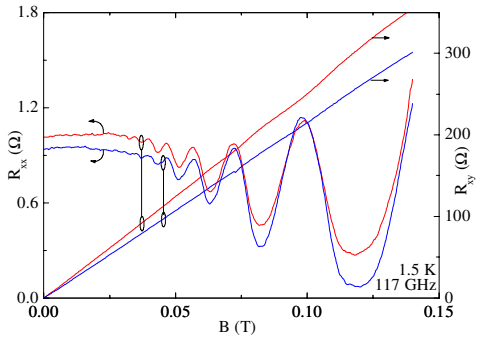

FIG. 4: The periodicity of radiation induced R_{xx} oscillations appears insensitive to the electron density, n. Here, increasing the slope of R_{xy} vs. B corresponds to decreasing n.

Fig. 1(b) shows R_{xx} under photoexcitation at 50 GHz. This panel includes DPPH-ESR field markers which identify B_f, $4/5B_f$, $B_f/2$ and $B_f/2.5$, for $f = 50$ GHz. These data show that, at $\pm B_f$, there is once again neither a maximum nor a minimum in the R_{xx}, as in Fig. 1(a). In addition, a zero-resistance state forms about the $\pm 4/5 B_f$ field marker, and there is neither a maximum nor a minimum in R_{xx} near the $\pm B_f/2$ marker.[1] Thus, the data of Fig. 1 indicate that the R_{xx} maxima do not coincide with B_f/j.[1, 2, 14, 16] They also confirm the absence of intrinsic sweep-direction dependent hysteretic effects.

Fig. 2(a) exhibits R_{xx} vs. B^{-1} at 50 GHz for several radiation intensities. This plot shows regular-in-B^{-1} R_{xx} oscillations with a number of "fixed points" where R_{xx} is independent of the microwave power. According to the theory,[8] the conductance under radiation should equal the dark conductance at $B_f/B = j$. We denote these as Integral Fixed Points (IFP). Experiment also indicates Half-Integral Fixed Points (HIFP) in the vicinity of $B_f/B = j + 1/2$.[12] The B-measurement of IFP's by ESR of DPPH is shown in Fig. 2(b). Here, the ESR of DPPH at $f_0 = 3.21$ GHz marks the first IFP in the R_{xx} data of Fig. 2(a). Fig. 2 (a) and (b) indicate that, when f_0 is selected to mark the first IFP, $f_0/2$ marks a B^{-1} that is slightly below the second IFP, suggesting a small correction. This correction is attributed here to the observed asymmetry between the resistance increase- and the resistance decrease- with respect to the dark value. That is, as the R_{xx} increase under excitation can easily exceed, in magnitude, the R_{xx} decrease, R_{xx} peaks tend to span a wider B^{-1} interval than the R_{xx} valleys. This tends to relocate the IFP to a slightly higher B^{-1} value, than where the condition $2\pi f/\omega_c = j$ actually holds true.

Another method for determining the period and the phase of the oscillations involves the application of a half-cycle plot, shown in Fig 2(c). Typically, the procedure assumes a cosine waveform. Thus, the R_{xx} maxima and minima are labelled by integers and half-integers, respectively. These labels, denoted here by the index k, are plotted vs. extremal values of B^{-1}, as in Fig. 2(c). A linear fit, k_{FIT}, then serves to determine the slope, $dk_{FIT}/dB^{-1} = B_f$, and the ordinate intercept. Here, in Fig. 2(c), the ordinate intercept at 1/4 demonstrates a 1/4 cycle phase shift of R_{xx} with respect to the assumed (cosine) waveform.[13] The residual difference, Δk, between k and k_{FIT} for the extrema and fixed points, has been shown in Fig. 2(d). Fig. 2(d) confirms a small phase distortion, discussed above, at the lowest fixed points. It also confirms that the $k = 1$ R_{xx} maximum, which tends to be upshifted from $B_f/B = 3/4$, is a special case,[12] see also Fig. 3(a).

There are two parameters in the half-cycle analysis: the intercept and the slope. Yet, the root-parameter in the slope is m^* since $B_f = 2\pi f m^*/e$, and f can be measured. The question then arises whether the measured m^* agrees with expectations.

In order to obtain a representative sampling of the phase and m^*/m, we have carried out a half-cycle analysis of a data set obtained over a range f. For this work, both the extrema and the fixed points were subjected to a separate half-cycle analysis at each frequency, as illustrated in Fig. 3(a) for $f = 103$ GHz. Since the analysis of the extrema has been discussed above, we note only that an analogous half-cycle analysis of the fixed points involves associating IFP's with integers and HIFP with half-integers, and plotting the resulting index k vs. B^{-1}.

A linear least squares fit served to determine the slope and the ordinate intercept of the k vs. B^{-1} plots, as in Fig. 3(a). The characteristic field, B_f, and m^*/m were extracted using $B_f = dk_{FIT}/dB^{-1}$, and $m^*/m = eB_f/(2\pi fm)$, where m is the electron mass. The resulting phase and m^*/m have been shown in Fig. 3(b) and Fig. 3(c). Fig. 3(b) shows that the average phase for the extrema is 0.24 ($\pm$ 0.015), which is 1/4 within uncertainty. On the other hand, Fig. 3(c) shows that the average phase for the fixed points is -0.015 ($\pm$ 0.012), which is approximately zero. Thus, the phase related results are broadly consistent with resistance minima at $B_f/B = j + 1/4$, resistance maxima at $B_f/B = j + 3/4$, IFP's at $B_f/B = j$, and HIFP's at $B_f/B = j+1/2$, for j = 1,2,3...[12] The residual difference, $\Delta k = k - k_{FIT}$, for the extrema and fixed points have been shown in Fig. 3(d) and Fig 3(e), respectively. Here, the scatter Δk spans a smaller band in Fig. 3(e) than in Fig. 3(d). Doublet formation on the $k = 2$ maximum at large f or low T, akin to "spin splitting," has been found to introduce scatter in Fig. 3(d).

So far as the mass ratios are concerned, Fig. 3(b) suggests $m^*/m = 0.0659$ ($\pm$ 0.0004), and Fig. 3(c) indicates that $m^*/m = 0.0656$ ($\pm$ 0.0006). These mass ratios are roughly 2% below the standard value, $m^*/m = 0.067$,[18] and 1% below our previously reported result, $m^*/m = 0.0663$.[1] Here, the difference between the average mass of Fig. 3 (b) and (c), and the standard value, appears to exceed the resolution limit of this experiment.

Mass corrections can originate from, for example, the polaron effect,[23] where an electron polarizes the lattice and creates phonons, and the dressing of the electron by the phonon cloud leads to a mass change, usually a mass increase. An observed mass reduction could be related to some such renormalization effect, if the associated effect is somehow switched off in this context, so that the measurement comes to reflect a bare mass, which then looks like a mass reduction. A theoretical study appears necessary to examine such a possibility. Band non-parabolicity can lead to a dependence of m^*/m on the electron density, n, or the Fermi energy. Fig. 4 shows, however, that the R_{xx} oscillation period remains unchanged as n is varied by $\approx$ 15 % using the persistent photo-effect.

In summary, we have demonstrated a f-independent 1/4 cycle phase shift of the extrema in the radiation induced oscillatory-magnetoresistance with respect to the $\omega/\omega_c = j$ or $B_f/B = j$ condition for $j \geq 1$.[4, 6, 8] We also find that m^*/m is 1 % smaller than previously reported,[1] and about 2 % smaller than the standard value.[18]

[1] R. G. Mani, J. H. Smet, K. von Klitzing, V. Narayanamurti, W. B. Johnson, and V. Umansky, Nature (London) **420**, 646 (2002).

[2] M. A. Zudov, R. R. Du, L. N. Pfeiffer and K. W. West, Phys. Rev. Lett. **90**, 046807 (2003).

[3] R. Fitzgerald, Phys. Today **56** (4), 24 (2003).

[4] V. I. Ryzhii, Fiz. Tverd. Tela (Leningrad) 11, 2577 (1969) [Sov. Phys. - Sol. St. **11**, 2078-2080 (1970)].

[5] J. C. Phillips, Sol. St. Comm. **127**, 233 (2003).

[6] A. C. Durst, S. Sachdev, N. Read, and S. M. Girvin, Phys. Rev. Lett. **91**, 086803 (2003).

[7] A. V. Andreev, I. L. Aleiner, and A. J. Millis, Phys. Rev. Lett. **91**, 056803 (2003).

[8] J. Shi and X. C. Xie, Phys. Rev. Lett. **91**, 086801 (2003).

[9] P. W. Anderson and W. F. Brinkman, cond-mat/0302129; K. N. Shrivastava, cond-mat/0302320; S. Mikhailov, cond-mat/0303130; P. H. Rivera and P. A. Schulz, cond-mat/0305019; R. Klesse and F. Merz, cond-mat/0305492; F. S. Bergeret, B. Huckestein, and A. F. Volkov, Phys. Rev. B **67**, 241303 (2003); A. A. Koulakov and M. E. Raikh, Phys. Rev. B **68**, 115324 (2003); V. Ryzhii and R. Suris, J. Phys. Condens. Mat. **15**, 6855 (2003); X. L. Lei and S. Y. Liu, Phys. Rev. Lett. **91**, 226805 (2003); I. A. Dmitriev, A. D. Mirlin, and D. G. Polyakov, Phys. Rev. Lett. **91**, 226802 (2003); V. Ryzhii and A. Satou, J. Phys. Soc. Jpn. **72**, 2718 (2003).

[10] R. E. Prange and S. M. Girvin, (eds) The Quantum Hall Effect, 2nd Ed., Springer-Verlag (New York, 1990).

[11] D. C. Tsui, H. Stormer, and A. C. Gossard, Phys. Rev. B **25**, 1405 (1982).

[12] R. G. Mani et al., cond-mat/0306388.

[13] R. G. Mani et al., cond-mat/0303034; cond-mat/0305507; cond-mat/0311010; cond-mat/0310474. R. G. Mani, Physica E (in press).

[14] M. A. Zudov, R. R. Du, J. A. Simmons, and J. L. Reno, Phys. Rev. B **64**, 201311 (2001).

[15] Minima about $B = [4/(4j-1)]B_f$ would also constitute a 1/4 cycle phase shift, although in the other direction.

[16] M. A. Zudov, cond-mat/0306508.

[17] R. G. Mani and K. von Klitzing, Appl. Phys. Lett. **64**, 3121 (1994); Appl. Phys. Lett. **64**, 1262 (1994); Z. Phys. B **92**, 335 (1993). R. G. Mani, J. Phys. Soc. Jpn. **65**, 1751 (1996); Phys. Rev. B **55**, 15838 (1997).

[18] S. M. Sze, Physics of Semicond. Devices, 2nd Edn. (Wiley, New York, 1981) p. 850; G. E. Stillman, C. M. Wolfe, and J. O. Dimmock, Sol. St. Comm. **7**, 921 (1969).

[19] 83650B Synthesized Swept-Signal Generator: Agilent Technologies, Palo Alto, CA 94303. www.agilent.com

[20] Series 072 Frequency Meter: Flann Microwave Inc., Bodwin, Cornwall PL31 2QL, UK. www.flann.com

[21] HP83711A Synthesized CW Generator: Agilent Technologies, Palo Alto, CA 94303. www.agilent.com

[22] R. E. Gerkin et al., J. Chem. Phys. **66**, 4166 (1997); F. J. Teran et al., cond-mat/0306634.

[23] D. M. Larsen, Phys. Rev. **135**, A419 (1964).